SCES726A - NOVEMBER 2008-REVISED NOVEMBER 2013

16-BIT DUAL-SUPPLY BUS TRANSCEIVER WITH CONFIGURABLE VOLTAGE TRANSLATION AND 3-STATE OUTPUTS

Check for Samples: SN74LVCH16T245-EP

FEATURES

- Control Inputs V_{IH}/V_{IL} Levels Are Referenced to V_{CCA} Voltage
- V_{CC} Isolation Feature If Either V_{CC} Input Is at GND, All Outputs Are in the High-Impedance State
- Overvoltage-Tolerant Inputs/Outputs Allow Mixed-Voltage-Mode Data Communications
- Fully Configurable Dual-Rail Design Allows Each Port to Operate Over the Full 1.65-V to 5.5-V Power-Supply Range
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

SUPPORTS DEFENSE, AEROSPACE, AND MEDICAL APPLICATIONS

- Controlled Baseline
- One Assembly/Test Site
- · One Fabrication Site
- Available in Military (-55°C/125°C)
 Temperature Range (1)
- Extended Product Life Cycle
- Extended Product-Change Notification
- Product Traceability
- (1) Custom temperature ranges available

DGV PACKAGE (TOP VIEW) 1DIR 🛭 48 10E 1B1 📙 2 47 1A1 1B2 📙 46 1A2 GND [4 45 GND 1B3 ∏ 5 44 1 1A3 1B4 🛮 43 1A4 6 V_{CCB} 42 V_{CCA} 1B5 🛮 8 41 1 1A5 1B6 L 40**□** 1A6 **GND** 10 39 GND 1B7 🛮 38 1A7 11 1B8 🛚 37 1A8 12 2B1 13 36 2A1 2B2 | | 14 35 2A2 **GND** 15 34 GND 2B3 🛮 16 33 2A3 2B4 | 17 32 2A4 V_{CCB} [] 31 V_{CCA} 18 2B5 19 30 2A5 2B6 🛮 20 29 2A6 GND 21 28 GND 22 2B7 [] 27 2A7 2B8 🛮 23 26 2A8 2DIR 🛮 24 25 2OE

DESCRIPTION

This 16-bit noninverting bus transceiver uses two separate configurable power-supply rails. The A port is designed to track V_{CCA} . V_{CCA} accepts any supply voltage from 1.65 V to 5.5 V. The B port is designed to track V_{CCB} . V_{CCB} accepts any supply voltage from 1.65 V to 5.5 V. This allows for universal low-voltage bidirectional translation between any of the 1.8-V, 2.5-V, 3.3-V, and 5-V voltage nodes.

The SN74LVCH16T245 is designed so that the control pins (1DIR, 2DIR, 1OE, and 2OE) are supplied by V_{CCA}.



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DESCRIPTION (CONTINUED)

The SN74LVCH16T245 is designed for asynchronous communication between two data buses. The logic levels of the direction-control (DIR) input and the output-enable (\overline{OE}) input activate either the B-port outputs or the A-port outputs or place both output ports into the high-impedance mode. The device transmits data from the A bus to the B bus when the B-port outputs are activated, and from the B bus to the A bus when the A-port outputs are activated. The input circuitry on both A and B ports is always active and must have a logic HIGH or LOW level applied to prevent excess I_{CC} and I_{CCZ} .

Active bus-hold circuitry holds unused or undriven data inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The V_{CC} isolation feature ensures that if either V_{CC} input is at GND, then all outputs are in the high-impedance state. The bus-hold circuitry on the powered-up side always stays active.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Table 1. ORDERING INFORMATION⁽¹⁾

T _A	PACKAGE ⁽	2)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
50°C to 125°C	TVSOP – DGV	Tape and reel	CLVCH16T245MDGVREP	LDHT245MEP
–50°C to 125°C	TSSOP - DGG	Tape and reel	CLVCH16T245MDGGREP	8UT245MEP

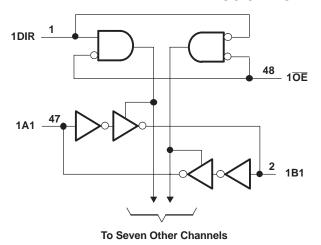
- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI Web site at www.ti.com.
- (2) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

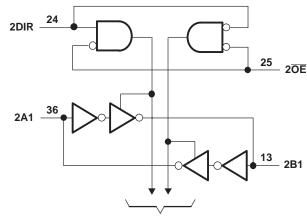
FUNCTION TABLE⁽¹⁾ (EACH 16-BIT SECTION)

CONTRO	L INPUTS	OUTPUT C	IRCUITS	OPERATION
ŌĒ	DIR	A PORT	B PORT	OPERATION
L	L	Enabled	Hi-Z	B data to A bus
L	Н	Hi-Z	Enabled	A data to B bus
Н	Х	Hi-Z	Hi-Z	Isolation

(1) Input circuits of the data I/Os are always active.

LOGIC DIAGRAM (POSITIVE LOGIC)





To Seven Other Channels

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Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CCA} V _{CCB}	Supply voltage range		-0.5	6.5	V
		I/O ports (A port)	-0.5	6.5	
V_{I}	Input voltage range ⁽²⁾	I/O ports (B port)	-0.5	6.5	V
		Control inputs	-0.5	6.5	
Vo	Voltage range applied to any output	A port	-0.5	6.5	V
	in the high-impedance or power-off state (2)	B port	-0.5	6.5	V
.,	Valence and the day of the second to the birth on law extend (2) (3)	A port	-0.5	V _{CCA} + 0.5	V
Vo	Voltage range applied to any output in the high or low state (2) (3)	B port	-0.5	V _{CCB} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through each V _{CCA} , V _{CCB} , and GND			±100	mA
θ_{JA}	Package thermal impedance (4)		58	°C/W	
T _{stg}	Storage temperature range	-65	150	°C	

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

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⁽²⁾ The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The output positive-voltage rating may be exceeded up to 6.5 V maximum if the output current rating is observed.

⁽⁴⁾ The package thermal impedance is calculated in accordance with JESD 51-7.



Recommended Operating Conditions⁽¹⁾ (2) (3)

			V _{CCI}	V _{cco}	MIN	MAX	UNIT
V_{CCA}	0 1 1				1.65	5.5	.,
V _{CCB}	Supply voltage				1.65	5.5	V
			1.65 V to 1.95 V		V _{CCI} × 0.65		
	High-level	5 (4)	2.3 V to 2.7 V		1.7		.,
V_{IH}	input voltage	Data inputs ⁽⁴⁾	3 V to 3.6 V		2		V
			4.5 V to 5.5 V		$V_{CCI} \times 0.7$		
			1.65 V to 1.95 V			$V_{CCI} \times 0.35$	
	Low-level	5 (4)	2.3 V to 2.7 V			0.7	.,
V _{IL}	input voltage	Data inputs ⁽⁴⁾	3 V to 3.6 V			0.8	V
			4.5 V to 5.5 V			$V_{CCI} \times 0.3$	
			1.65 V to 1.95 V		$V_{CCA} \times 0.65$		
	High-level	Control inputs	2.3 V to 2.7 V		1.7		
V_{IH}	input voltage	(referenced to V _{CCA}) ⁽⁵⁾	3 V to 3.6 V		2		V
			4.5 V to 5.5 V		$V_{CCA} \times 0.7$		
			1.65 V to 1.95 V			V _{CCA} × 0.35	
	Low-level	Control inputs	2.3 V to 2.7 V			0.7	.,
V_{IL}	input voltage	(referenced to V _{CCA}) ⁽⁵⁾	3 V to 3.6 V			0.8	V
			4.5 V to 5.5 V			V _{CCA} × 0.3	
V _I	Input voltage	Control inputs			0	5.5	V
,		Active state			0	V _{cco}	.,
V _{I/O}	Input/output voltage	3-State			0	5.5	V
		!		1.65 V to 1.95 V		-4	
	LP-de last a set and a set			2.3 V to 2.7 V		-8	4
Юн	High-level output curr	ent		3 V to 3.6 V		-24	mA
				4.5 V to 5.5 V		-32	
				1.65 V to 1.95 V		4	
ı				2.3 V to 2.7 V		8	A
OL	Low-level output curr	ent		3 V to 3.6 V		24	mA
				4.5 V to 5.5 V		32	
			1.65 V to 1.95 V			20	
۸+/۸۰۰	Input transition	Data inputa	2.3 V to 2.7 V			20	no/\/
∆t/Δv	rise or fall rate	Data inputs	3 V to 3.6 V			10	ns/V
			4.5 V to 5.5 V			5	
T _A	Operating free-air ten	nperature			-40	85	°C

V_{CCI} is the V_{CC} associated with the data input port.

V_{CCI} is the V_{CC} associated with the data input port.
 V_{CCO} is the V_{CC} associated with the output port.
 All unused control inputs of the device must be held at V_{CCA} GND to ensure proper device operation and minimize power consumption. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.
 For V_{CCI} values not specified in the data sheet, V_{IH} min = V_{CCI} × 0.7 V, V_{IL} max = V_{CCI} × 0.3 V.
 For V_{CCA} values not specified in the data sheet, V_{IH} min = V_{CCA} × 0.7 V, V_{IL} max = V_{CCA} × 0.3 V.

Electrical Characteristics (1) (2)

over recommended operating free-air temperature range (unless otherwise noted)

PAF	RAMETER	TEST COND	ITIONS	V _{CCA}	V _{CCB}	MIN	TYP	MAX	MIN	MAX	UNIT
		$I_{OH} = -100 \mu A$,	$V_I = V_{IH}$	1.65 V to 4.5 V	1.65 V to 4.5 V				V _{CCO} - 0.1		
		$I_{OH} = -4 \text{ mA},$	$V_I = V_{IH}$	1.65 V	1.65 V				1.2		
/ _{OH}		$I_{OH} = -8 \text{ mA},$	$V_I = V_{IH}$	2.3 V	2.3 V				1.9		V
		$I_{OH} = -24 \text{ mA},$	$V_I = V_{IH}$	3 V	3 V				2.4		
		$I_{OH} = -32 \text{ mA},$	$V_I = V_{IH}$	4.5 V	4.5 V				3.8		
		$I_{OL} = 100 \mu A$,	$V_I = V_{IL}$	1.65 V to 4.5 V	1.65 V to 4.5 V					0.1	
		$I_{OL} = 4 \text{ mA},$	$V_I = V_{IL}$	1.65 V	1.65 V					0.45	
V_{OL}		$I_{OL} = 8 \text{ mA},$	$V_I = V_{IL}$	2.3 V	2.3 V					0.3	V
		I _{OL} = 24 mA,	$V_I = V_{IL}$	3 V	3 V					0.55	
		I _{OL} = 32 mA,	$V_I = V_{IL}$	4.5 V	4.5 V					0.55	
lı	Control inputs	V _I = V _{CCA} or GND		1.65 V to 5.5 V	1.65 V to 5.5 V		±0.5	±1		±2	μΑ
	•	V _I = 0.58 V		1.65 V	1.65 V				15		
(3)		V _I = 0.7 V		2.3 V	2.3 V				45		
BHL (3)		V _I = 0.8 V		3 V	3 V				75		μA
		V _I = 0.1.35 V		4.5 V	4.5 V				100		
		V _I = 1.07 V		1.65 V	1.65 V				-15		
(4)	١	V _I = 1.7 V		2.3 V	2.3 V				-45		
внн (4))	V _I = 2 V		3 V	3 V				- 75		μΑ
		V _I = 3.15 V		4.5 V	4.5 V				-100		
				1.95 V	1.95 V				200		
(5)	\/ 0 to \/		2.7 V	2.7 V				300		
BHLO (0)	$V_I = 0$ to V_{CC}		3.6 V	3.6 V				500		μA
				5.5 V	5.5 V				900		
				1.95 V	1.95 V				-200		
	(6)			2.7 V	2.7 V				-300		
внно ((•)	$V_I = 0$ to V_{CC}		3.6 V	3.6 V				-500		μA
				5.5 V	5.5 V				-900		
	A port	\\ - \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\	M	0 V	0 to 5.5 V		±0.5	±1		±2	
off	B port	V_1 or $V_0 = 0$ to 5.5	V	0 to 5.5 V	0 V		±0.5	±1		±2	μA
	A or B port	$V_O = V_{CCO}$ or	OE = V _{IH}	1.65 V to 5.5 V	1.65 V to 5.5 V			±1		±2	
OZ	B port	$\begin{array}{l} \text{GND,} \\ V_{\text{I}} = V_{\text{CCI}} \text{ or GND} \end{array}$	$\overline{OE} = don't$	0 V	5.5 V			±1		±2	μA
	A port	1 = 1 CC 01 O11D	care	5.5 V	0 V			±1		±2	
				1.65 V to 5.5 V	1.65 V to 5.5 V					20	
CCA		$V_I = V_{CCI}$ or GND,	I _O = 0	5 V	0 V					20	μΑ
				0 V	5 V					-2	
				1.65 V to 5.5 V	1.65 V to 5.5 V					20	
ССВ		$V_I = V_{CCI}$ or GND,	I _O = 0	5 V	0 V					-2	μΑ
			-	0 V	5 V					20	-
I _{CCA} +	Icce	$V_I = V_{CCI}$ or GND,	$I_0 = 0$	1.65 V to 5.5 V	1.65 V to 5.5 V					30	μA

 ⁽¹⁾ V_{CCO} is the V_{CC} associated with the output port.
 (2) V_{CCI} is the V_{CC} associated with the input port.
 (3) The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{IL} max.

The bus-hold circuit can source at least the minimum high sustaining current at V_{IH} min. I_{BHH} should be measured after raising V_{IN} to V_{CC} and then lowering it to V_{IH} min.

An external driver must source at least I_{BHLO} to switch this node from low to high.

An external driver must sink at least I_{BHHO} to switch this node from high to low.



Electrical Characteristics(1) (2) (continued)

over recommended operating free-air temperature range (unless otherwise noted)

PAR	AMETER	TEST CONDITIONS	V _{CCA}	V _{CCB}	MIN TYP MAX	MIN MAX	UNIT
ΔI_{CCA}	DIR	DIR at V _{CCA} - 0.6 V, B port = open, A port at V _{CCA} or GND	3 V to 5.5 V	3 V to 5.5 V		50	μΑ
Ci	Control inputs	V _I = V _{CCA} or GND	3.3 V	3.3 V	4	5	pF
C _{io}	A or B port	$V_O = V_{CCA/B}$ or GND	3.3 V	3.3 V	8.5	10	pF

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 1.8 V ± 0.15 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO (OUTPUT)	V _{CCB} = ± 0.15		V _{CCB} = ± 0.2		V _{CCB} = ± 0.3		V _{CCB} = ± 0.5		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	Α Α	В	1.7	21.9	1.3	9.2	1	7.4	0.4	7.1	ns
t _{PHL}	^	Ь	1.7	21.3	1.5	3.2		7.4	0.4	7.1	113
t _{PLH}	В	Α	0.9	23.8	0.8	23.8	0.7	23.4	0.7	23.4	ns
t _{PHL}	Б	A	0.9	23.0	0.6	23.0	0.7	23.4	0.7	23.4	115
t_{PHZ}	 OE	Α	1.5	29.6	1.5	29.4	1.5	29.3	1.4	29.2	ns
t_{PLZ}	OE	A	1.5	29.0	1.5	29.4	1.5	29.3	1.4	29.2	115
t_{PHZ}	<u>OE</u>	В	2.4	32.2	1.9	13.1	1.7	12	1.3	10.3	ns
t_{PLZ}	OL	В	2.4	32.2	1.9	13.1	1.7	12	1.3	10.5	115
t _{PZH}	 OE	А	0.4	24	0.4	23.8	0.4	23.7	0.4	23.7	no
t _{PZL}	OE .	A	0.4	24	0.4	23.0	0.4	23.7	0.4	23.1	ns
t _{PZH}	 OE	В	1.8	32	1.5	18	1.2	12.6	0.9	10.8	ns
t_{PZL}	OE .	В	1.0	32	1.5	10	1.2	12.0	0.9	10.0	115

Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	FROM TO (OUTPUT)		V _{CCB} = 1.8 V ± 0.15 V		V _{CCB} = 2.5 V ± 0.2 V		3.3 V 3 V	V _{CCB} = ± 0.5		UNIT
	(INPOT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	A	В	1.5	21.4	1.2	9	0.8	6.2	0.6	4.8	ns
t _{PHL}	^	В	1.5	21.4	1.2	9	0.6	0.2	0.0	4.0	115
t _{PLH}	В	Α	1.2	9.3	1	9.1	1	8.9	0.9	8.8	ns
t _{PHL}	Ь	^	1.2	9.5	'	3.1	<u>'</u>	0.9	0.9	0.0	113
t_{PHZ}	OE	Α	1.4	9	1.4	9	1.4	9	1.4	9	ns
t_{PLZ}	OL	Α	1.4	9	1.4	Э	1.4	9	1.4	9	115
t_{PHZ}	OE	В	2.3	29.6	1.8	11	1.7	9.3	0.9	6.9	ns
t_{PLZ}	OL	В	2.0	29.0	1.0	''	1.7	9.5	0.9	0.9	113
t_{PZH}	OE	Α	1	10.9	1	10.9	1	10.9	1	10.9	ns
t _{PZL}	OL .	Α	ľ	10.9	Į.	10.9	'	10.9		10.9	115
t_{PZH}	OE	В	1.7	28.2	1.5	12.9	1.2	9.4	1	6.9	ns
t_{PZL}	OE .	В	1.7	20.2	1.5	12.9	1.2	9.4	1	0.9	115

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Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO (OUTPUT)	V _{CCB} = ± 0.15		V _{CCB} = ± 0.2		V _{CCB} = ± 0.3		V _{CCB} = ± 0.5		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	A	В	1.6	21.2	1.1	8.8	0.8	6.2	0.6	4.4	ns
t _{PHL}	^	В	1.0	21.2	1.1	0.0	0.6	0.2	0.0	4.4	115
t _{PLH}	В	Α	0.8	7.2	0.8	6.2	0.7	6.1	0.6	6	ns
t _{PHL}	Ь	A	0.8	1.2	0.6	0.2	0.7	0.1	0.0	0	115
t_{PHZ}	ŌĒ	Α	1.6	8.2	1.6	8.2	1.6	8.2	1.6	8.2	ns
t_{PLZ}	OL.	٨	1.0	0.2	1.0	0.2	1.0	0.2	1.0	0.2	113
t_{PHZ}	ŌĒ	В	2.1	29	1.7	10.3	1.5	8.8	0.8	6.3	ns
t_{PLZ}	OL	Б	2.1	23	1.7	10.5	1.5	0.0	0.0	0.5	115
t _{PZH}	ŌĒ	Α	0.8	7.8	0.8	8.1	0.8	8.1	0.8	8.1	ns
t_{PZL}	OL .	٨	0.0	7.0	0.0	0.1	0.0	0.1	0.0	0.1	113
t _{PZH}	 OE	В	1.8	27.7	1.4	12.4	1.1	8.5	0.8	6.4	ns
t_{PZL}		J	1.0	۲۱.۱	1.4	12.7		0.5	0.0	0.4	113

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO (OUTPUT)	V _{CC} = 1 ± 0.15		V _{CC} = : ± 0.2		V _{CC} = ± 0.3		V _{CC} = ± 0.5		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	Α	В	1.5	21.4	1	8.8	0.7	6	0.4	4.2	ns
t _{PHL}	Α	В	1.5	21.4		0.0	0.7	O	0.4	4.2	115
t _{PLH}	В	Α	0.7	7	0.4	4.8	0.3	4.5	0.3	4.3	ns
t _{PHL}	Ь	A	0.7		0.4	4.0	0.3	4.5	0.3	4.3	115
t _{PHZ}	ŌĒ	Α	0.3	5.4	0.3	5.4	0.3	5.4	0.3	5.4	ns
t_{PLZ}	OL	Α	0.5	3.4	0.3	5.4	0.3	5.4	0.3	5.4	115
t_{PHZ}	ŌĒ	В	2	28.7	1.8	9.7	1.4	8	0.7	5.7	ns
t_{PLZ}	OL	В	2	20.7	1.0	9.1	1.4	0	0.7	3.7	115
t _{PZH}	ŌĒ	Α	0.7	6.4	0.7	6.4	0.7	6.4	0.7	6.4	ns
t _{PZL}	OE	A	0.7	0.4	0.7	0.4	0.7	0.4	0.7	0.4	115
t _{PZH}	ŌĒ	В	1.5	27.6	1.3	11.4	1	8.1	0.9	6	ns
t _{PZL}	OE.	Б	1.5	27.0	1.3	11.4	'	0.1	0.9	O	115

Operating Characteristics

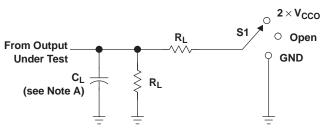
T_∆ = 25**�**C

1A - 20	• •						
	PARAMETER	TEST CONDITIONS	V _{CCA} = V _{CCB} = 1.8 V	$V_{CCA} = V_{CCB} = 2.5 V$	V _{CCA} = V _{CCB} = 3.3 V	V _{CCA} = V _{CCB} = 5 V	UNIT
o (1)	A-port input, B-port output		2	2	2	3	
C _{pdA} (1)	B-port input, A-port output	$C_L = 0$,	18	19	19	22	
c (1)	A-port input, B-port output	f = 10 MHz, $t_r = t_f = 1 \text{ ns}$	18	19	20	22	pF
C _{pdB} (1)	B-port input, A-port output		2	2	2	2	

(1) Power dissipation capacitance per transceiver



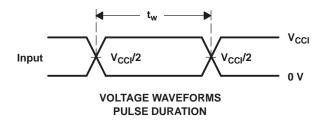
PARAMETER MEASUREMENT INFORMATION

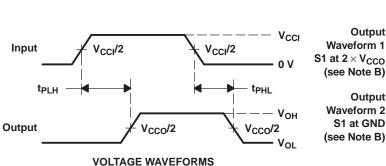


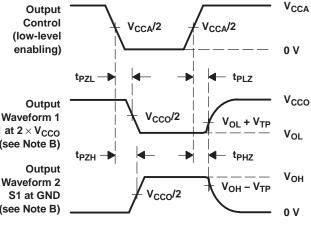
TEST	S 1
t _{pd}	Open
t _{PLZ} /t _{PZL}	2×V _{CCO}
t _{PHZ} /t _{PZH}	GND

LOAD CIRCUIT

V _{CCO}	CL	R _L	V_{TP}
1.8 V \pm 0.15 V	15 pF	2 k Ω	0.15 V
2.5 V \pm 0.2 V	15 pF	2 k Ω	0.15 V
3.3 V \pm 0.3 V	15 pF	2 k Ω	0.3 V
5 V ± 0.5 V	15 pF	2 k Ω	0.3 V







VOLTAGE WAVEFORMS

ENABLE AND DISABLE TIMES

NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $dv/dt \geq$ 1 V/ns, $dv/dt \geq$ 1 V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. V_{CCI} is the V_{CC} associated with the input port.
- I. V_{CCO} is the V_{CC} associated with the output port.

PROPAGATION DELAY TIMES

J. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms







10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CLVCH16T245MDGGREP	ACTIVE	TSSOP	DGG	48	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	8UT245MEP	Samples
CLVCH16T245MDGVREP	ACTIVE	TVSOP	DGV	48	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	LDHT245MEP	Samples
V62/09605-01XE	ACTIVE	TSSOP	DGG	48	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	8UT245MEP	Samples
V62/09605-01YE	ACTIVE	TVSOP	DGV	48	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	LDHT245MEP	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Dec-2020

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OTHER QUALIFIED VERSIONS OF SN74LVCH16T245-EP:

Catalog: SN74LVCH16T245

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

www.ti.com 3-Jun-2022

TAPE AND REEL INFORMATION



TAPE DIMENSIONS + K0 - P1 - B0 W Cavity - A0 -

A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CLVCH16T245MDGGREP	TSSOP	DGG	48	2000	330.0	24.4	8.6	13.0	1.8	12.0	24.0	Q1
CLVCH16T245MDGVREP	TVSOP	DGV	48	2000	330.0	16.4	7.1	10.2	1.6	12.0	16.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CLVCH16T245MDGGREP	TSSOP	DGG	48	2000	367.0	367.0	45.0
CLVCH16T245MDGVREP	TVSOP	DGV	48	2000	356.0	356.0	35.0



SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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